

High voltage fast-switching NPN power transistor

Preliminary Data

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting
- Electronic transformer for halogen lamps



The device is manufactured using high voltage Multi Epitaxial Planar technology for high switching speeds. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a satisfactory RBSOA.

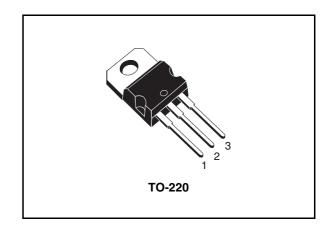


Figure 1. Internal schematic diagrams

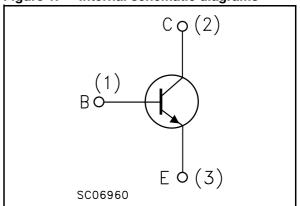


Table 1. Device summary

| Oder code | Marking | Package | Packing |
|-----------|---------|---------|---------|
| TR236 | TR236 | TO-220 | Tube |

Electrical ratings TR236

1 Electrical ratings

Table 2. Absolute maximum rating

| Symbol | Parameter | Value | Unit |
|------------------|---|----------------------|------|
| V _{CES} | Collector-emitter voltage (V _{BE} = 0) | 700 | V |
| V _{CEO} | Collector-emitter voltage (I _B = 0) | 400 | V |
| V _{EBO} | Emitter-base voltage $(I_C = 0, I_B = 2A, t_p < 10\mu s)$ | V _{(BR)EBO} | V |
| I _C | Collector current (I _C = 0) | 4 | Α |
| I _{CM} | Collector peak current (t _P < 5ms) | 8 | Α |
| I _B | Base current | 2 | Α |
| I _{BM} | Base peak current (t _P < 5ms) | 4 | Α |
| P _{tot} | Total dissipation at T _c ≤25°C | 70 | W |
| T _{stg} | Storage temperature | -65 to 150 | °C |
| T _J | Max. operating junction temperature | 150 | °C |

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|--------------------------------------|---|---|---------|------------|------------|----------|
| I _{CES} | Collector cut-off current (V _{BE} =0) | V _{CE} =700 V V _{CE} =700 V T _C = 125°C | | | 0.1 0.5 | mA mA |
| I _{CEO} | Collector cut-off current (I _B =0) | V _{CE} =400 V | | | 0.25 | mA |
| V _{(BR)EBO} | Emitter-base breakdown voltage (I _C = 0) | I _E =10 mA | 9 | | 18 | V |
| V _{CEO(sus)} ⁽¹⁾ | Collector-emitter sustaining voltage (I _B = 0) | I _C =10 mA | 400 | | | V |
| V _{CE(sat)} (1) | Collector-emitter saturation voltage | $I_C = 0.8 \text{ A}$ $I_B = 0.1 \text{ A}$ $I_C = 2.5 \text{ A}$ $I_B = 0.6 \text{ A}$ | | | 1.1 1.3 | V V |
| V _{BE(sat)} (1) | Base-emitter saturation voltage | $I_C = 1 A$ $I_B = 0.2 A$ $I_C = 2.5 A$ $I_B = 0.5 A$ | | | 1.2 1.3 | V V |
| h _{FE} | DC current gain | $I_C = 10 \text{ mA}$ $V_{CE} = 5 \text{ V}$ $I_C = 2.5 \text{ A}$ $V_{CE} = 5 \text{ V}$ | 10 8 | | 28 | |
| t _s | Inductive load Storage time Fall time | $V_{CC} = 200 \text{ V}$ $I_{C} = 2 \text{ A}$ $I_{B1} = 0.4 \text{ A}$ $V_{BE(off)} = -5 \text{ V}$ $R_{BB} = 0 \Omega$ $L = 200 \mu H$ (see <i>Figure 2</i>) | | 0.6 0.1 | | μs μs |

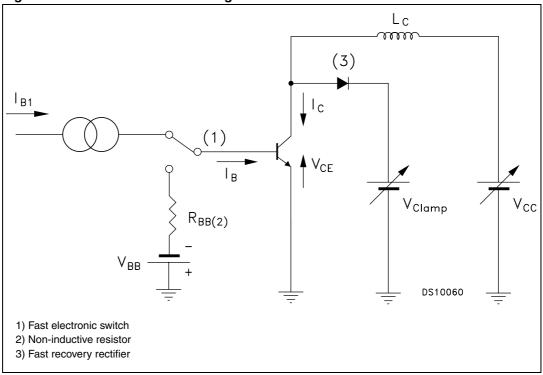
^{1.} Pulsed duration = 300ms, duty cycle ≤ 1.5%

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Electrical characteristics TR236

2.1 Test circuits

Figure 2. Inductive load switching test circuit



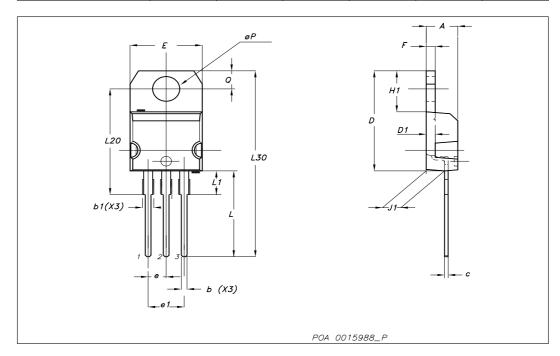
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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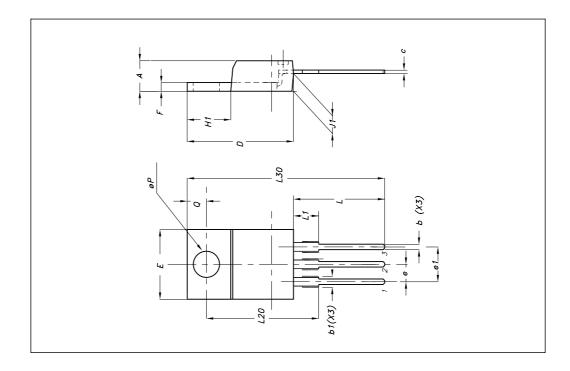
TO-220 mechanical data

| Dim | mm | | | inch | | |
|-------|-------|-------|-------|-------|-------|-------|
| Dilli | Min | Тур | Max | Min | Тур | Max |
| Α | 4.40 | | 4.60 | 0.173 | | 0.181 |
| b | 0.61 | | 0.88 | 0.024 | | 0.034 |
| b1 | 1.14 | | 1.70 | 0.044 | | 0.066 |
| С | 0.49 | | 0.70 | 0.019 | | 0.027 |
| D | 15.25 | | 15.75 | 0.6 | | 0.62 |
| D1 | | 1.27 | | | 0.050 | |
| E | 10 | | 10.40 | 0.393 | | 0.409 |
| е | 2.40 | | 2.70 | 0.094 | | 0.106 |
| e1 | 4.95 | | 5.15 | 0.194 | | 0.202 |
| F | 1.23 | | 1.32 | 0.048 | | 0.051 |
| H1 | 6.20 | | 6.60 | 0.244 | | 0.256 |
| J1 | 2.40 | | 2.72 | 0.094 | | 0.107 |
| L | 13 | | 14 | 0.511 | | 0.551 |
| L1 | 3.50 | | 3.93 | 0.137 | | 0.154 |
| L20 | | 16.40 | | | 0.645 | |
| L30 | | 28.90 | | | 1.137 | |
| ØP | 3.75 | | 3.85 | 0.147 | | 0.151 |
| Q | 2.65 | | 2.95 | 0.104 | | 0.116 |



TO-220 Mechanical Data "Option 1"

| DIM. | mm. | | | |
|-------|-------|-------|-------|--|
| DIWI. | MIN. | TYP | MAX. | |
| Α | 4.40 | | 4.60 | |
| b | 0.61 | | 0.88 | |
| b1 | 1.15 | | 1.70 | |
| С | 0.37 | | 0.43 | |
| D | 15.25 | | 15.75 | |
| E | 10 | | 10.40 | |
| е | 2.40 | | 2.70 | |
| e1 | 4.95 | | 5.15 | |
| F | 1.23 | | 1.32 | |
| H1 | 6.20 | | 6.60 | |
| J1 | 2.40 | | 2.72 | |
| L | | 12.87 | | |
| L1 | | 3.25 | | |
| L20 | | 16.40 | | |
| L30 | | 28.90 | | |
| øΡ | 3.75 | | 3.85 | |
| Q | 2.65 | | 2.95 | |



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Revision history TR236

4 Revision history

Table 4. Document revision history

| Date | Revision | Changes |
|-------------|----------|------------------|
| 08-Oct-2007 | 1 | Initial release. |

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